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Renesas Technology Corp. Customer Support Dept. April 1, 2003



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Octal Buffer/Line Driver with 3-State Output



ADE-205-382 (Z) 1st. Edition Sep. 2000

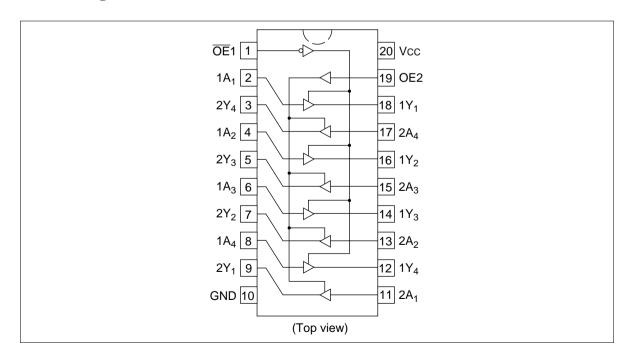
#### **Description**

The HD74AC241/HD74ACT241 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus-oriented transmitter or receiver which provides improved PC board density.

#### **Features**

- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Outputs Source/Sink 24 mA
- HD74ACT241 has TTL-Compatible Inputs

#### **Pin Arrangement**



#### **Truth Tables**

Inputs	Outputs (Pins 12, 14, 16, 18)

OE <sub>1</sub>	Α	Y	
L	L	L	
L	Н	Н	
Н	Х	Z	

#### Inputs Outputs (Pins 3, 5, 7, 9)

OE <sub>2</sub>	A	Υ
Н	L	L
Н	Н	Н
L	X	Z

H: High Voltage Level
L: Low Voltage Level

X : ImmaterialZ : High Impedance

## DC Characteristics (unless otherwise specified)

Item	Symbol	Max	Unit	Condition
Maximum quiescent supply current	I <sub>cc</sub>	80	μΑ	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 \text{ V}$ , Ta = Worst case
Maximum quiescent supply current	I <sub>cc</sub>	8.0	μΑ	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 \text{ V}$ , Ta = 25°C
Maximum additional I <sub>cc</sub> /input (HD74ACT241)	I <sub>CCT</sub>	1.5	mA	$V_{IN} = V_{CC} - 2.1 \text{ V}, V_{CC} = 5.5 \text{ V},$ Ta = Worst case

#### **AC Characteristics: HD74AC241**

			Ta = +25°C C <sub>L</sub> = 50 pF		Ta = $-40^{\circ}$ C to $+85^{\circ}$ C C <sub>L</sub> = 50 pF			
Item	Symbol	V <sub>cc</sub> (V)*1	Min	Тур	Max	Min	Max	Unit
Propagation delay	t <sub>PLH</sub>	3.3	1.0	6.0	9.0	1.0	10.0	ns
Data to output		5.0	1.0	5.0	7.0	1.0	7.5	<del></del>
Propagation delay	t <sub>PHL</sub>	3.3	1.0	6.0	9.0	1.0	10.5	ns
Data to output		5.0	1.0	4.5	7.0	1.0	7.5	<del>_</del>
Output enable time	t <sub>zH</sub>	3.3	1.0	6.5	12.5	1.0	13.0	ns
		5.0	1.0	5.5	9.0	1.0	9.5	<del>_</del>
Output enable time	t <sub>zL</sub>	3.3	1.0	7.0	12.0	1.0	13.0	ns
		5.0	1.0	5.5	9.0	1.0	9.5	<del>_</del>
Output disable time	t <sub>HZ</sub>	3.3	1.0	8.0	12.0	1.0	12.5	ns
		5.0	1.0	6.5	10.0	1.0	10.5	_
Output disable time	t <sub>LZ</sub>	3.3	1.0	7.0	12.5	1.0	13.5	ns
		5.0	1.0	6.0	10.0	1.0	10.5	_

Note: 1. Voltage Range 3.3 is  $3.3 \text{ V} \pm 0.3 \text{ V}$ Voltage Range 5.0 is  $5.0 \text{ V} \pm 0.5 \text{ V}$ 

#### **AC Characteristics: HD74ACT241**

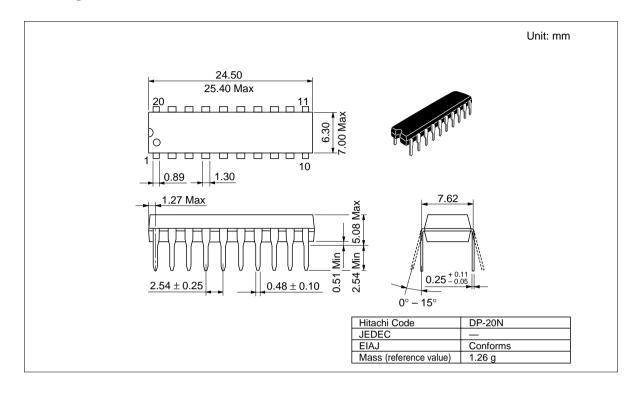
			Ta = +25°C C <sub>L</sub> = 50 pF		Ta = $-40^{\circ}$ C to $+85^{\circ}$ C C <sub>L</sub> = 50 pF			
Item	Symbol	V <sub>cc</sub> (V)*1	Min	Тур	Max	Min	Max	Unit
Propagation delay Data to output	t <sub>PLH</sub>	5.0	1.0	6.5	9.0	1.0	10.0	ns
Propagation delay Data to output	t <sub>PHL</sub>	5.0	1.0	7.0	9.0	1.0	10.0	ns
Output enable time	$\mathbf{t}_{ZH}$	5.0	1.0	6.0	9.0	1.0	10.0	ns
Output enable time	$t_{zL}$	5.0	1.0	7.0	10.0	1.0	11.0	ns
Output disable time	t <sub>HZ</sub>	5.0	1.0	8.0	10.5	1.0	11.5	ns
Output disable time	$t_{\scriptscriptstyleLZ}$	5.0	1.0	7.0	10.5	1.0	11.5	ns

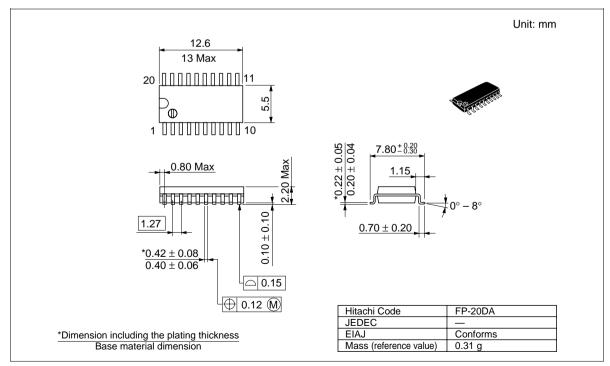
Note: 1. Voltage Range 5.0 is 5.0 V  $\pm$  0.5 V

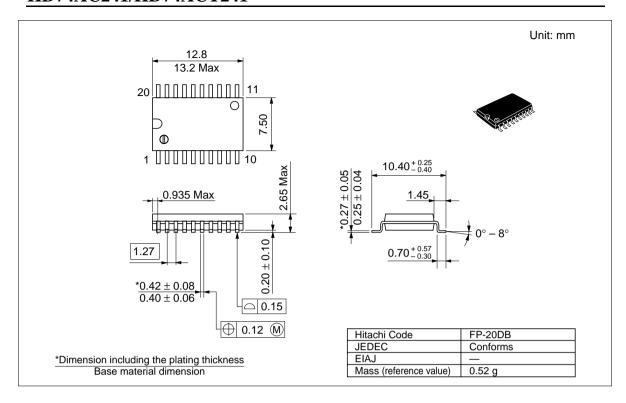
## Capacitance

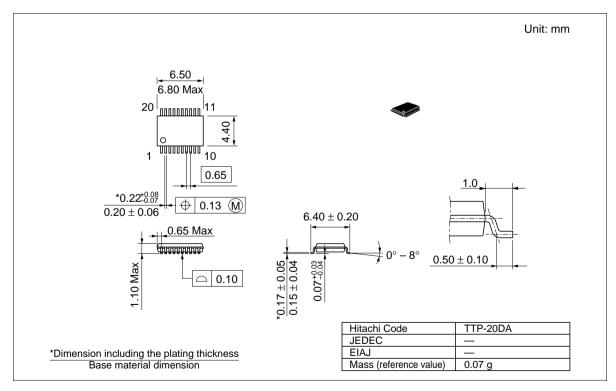
Item	Symbol	Тур	Unit	Condition	
Input capacitance	C <sub>IN</sub>	4.5	pF	$V_{CC} = 5.5 \text{ V}$	-
Power dissipation capacitance	$C_{\mathtt{PD}}$	45.0	pF	$V_{cc} = 5.0 \text{ V}$	_

#### **Package Dimensions**









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